

## AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 100 A



AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	100 A
$V_R$	150 V
Package	AAP Gen 7 (TO-240AA)
Circuit configuration	Two diodes doubler circuit

### MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- 175 °C  $T_J$  operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT

### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS209.. Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	100	A
$V_{RRM}$		150	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	11 300	A
$V_F$	100 A <sub>pk</sub> , $T_J = 125 \text{ }^\circ\text{C}$	0.85	V
$T_J$	Range	-55 to +175	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-VSKDS209/150	UNITS
Maximum DC reverse voltage	$V_R$	150	V
Maximum working peak reverse voltage	$V_{RWM}$		



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per leg	$I_{F(AV)}$	50 % duty cycle at $T_C = 113\text{ }^\circ\text{C}$ , rectangular waveform		100	
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu\text{s}$ sine or 3 $\mu\text{s}$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	11 300	A
		10 ms sine or 6 ms rect. pulse		1600	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25\text{ }^\circ\text{C}$ , $I_{AS} = 1.8\text{ A}$ , $L = 10\text{ mH}$		15	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{s}$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		1	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	100 A	$T_J = 25\text{ }^\circ\text{C}$	1.01	V
		200 A		1.35	
		100 A	$T_J = 125\text{ }^\circ\text{C}$	0.85	
		200 A		1.13	
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	6	mA
		$T_J = 125\text{ }^\circ\text{C}$		85	
Maximum junction capacitance	$C_T$	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		3000	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	$dV/dt$	Rated $V_R$		10 000	V/ $\mu\text{s}$
Maximum RMS insulation voltage	$V_{INS}$	50 Hz		3000 (1 min)	V
				3600 (1 s)	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$			-55 to +175	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	$R_{thJC}$	DC operation		0.52	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink per module	$R_{thCS}$			0.1	
Approximate weight				75	g
				2.7	oz.
Mounting torque $\pm 10\%$	to heatsink	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.		4	Nm
	busbar			3	
Case style		JEDEC <sup>®</sup>		TO-240AA compatible	

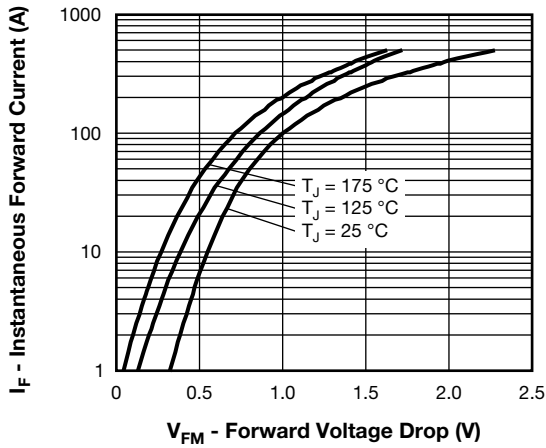


Fig. 1 - Maximum Forward Voltage Drop Characteristics

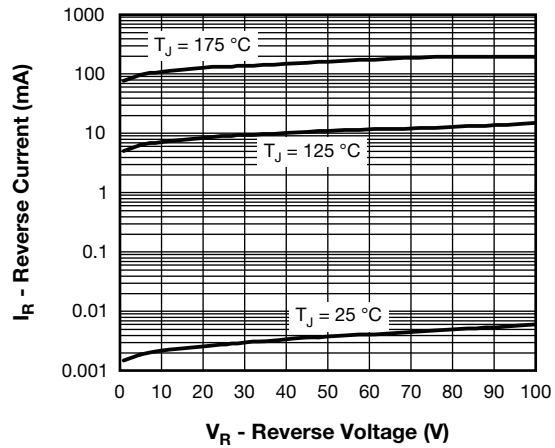


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

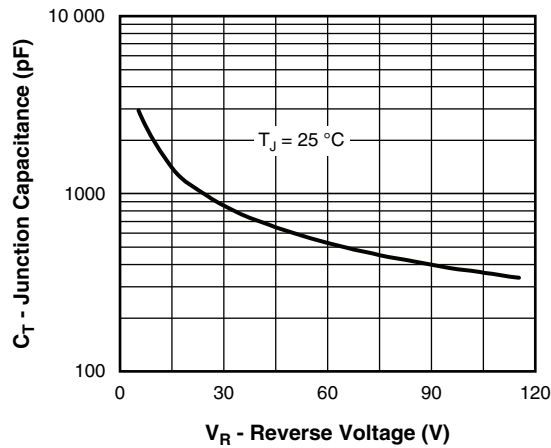


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

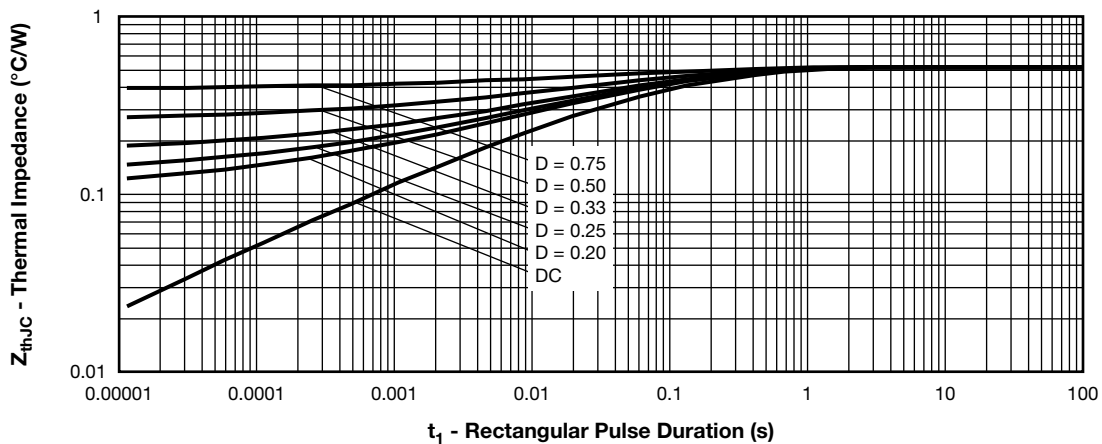


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

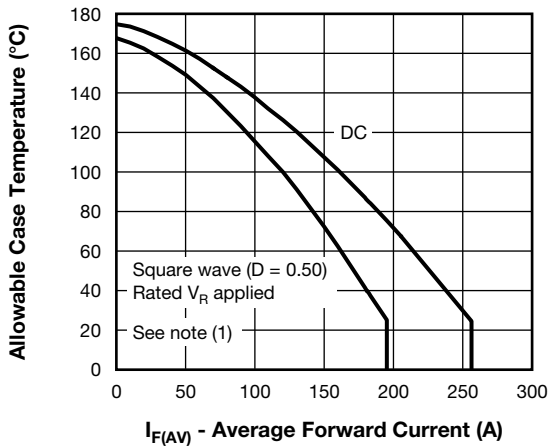


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

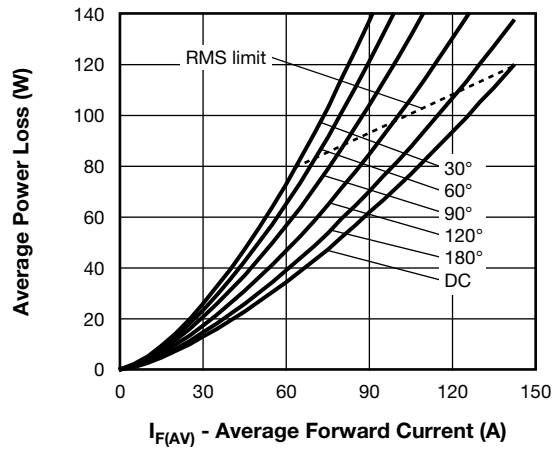


Fig. 6 - Forward Power Loss Characteristics

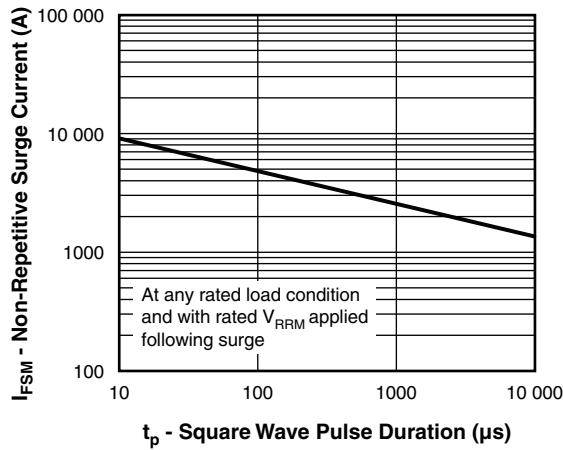


Fig. 7 - Maximum Non-Repetitive Surge Current

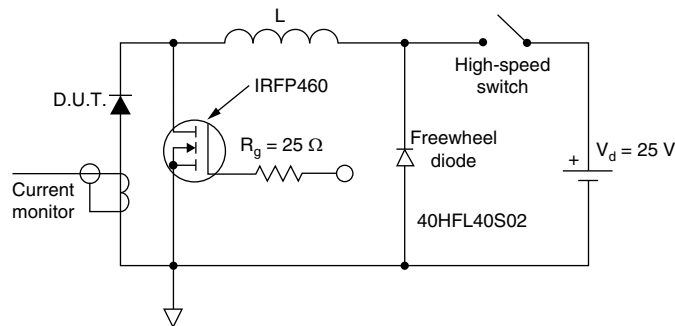
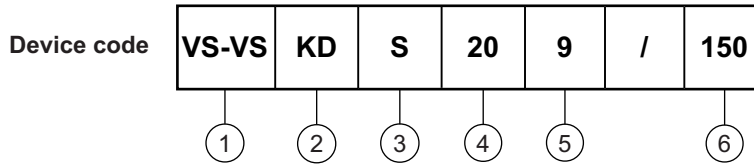


Fig. 8 - Unclamped Inductive Test Circuit

**Note**

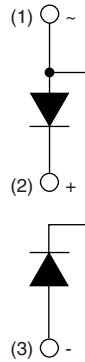
- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{d_{REV}}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

**ORDERING INFORMATION TABLE**



- 1 - VS-VS = Vishay Semiconductors product
- 2 - Circuit configuration:  
KD = ADD-A-PAK - 2 diodes doubler circuit
- 3 - S = Schottky diode
- 4 - Average current rating (20 = 200 A)
- 5 - Product silicon identification
- 6 - Voltage rating (150 = 150 V)

**CIRCUIT CONFIGURATION**



LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95369">www.vishay.com/doc?95369</a>



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